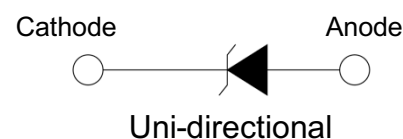


**HF** **RoHS** **Pb**

## Features

- Peak power dissipation 400W @10 x 1000 us Pulse
- Low profile package.
- Excellent clamping capability.
- Glass passivated junction.
- Fast response time: typically less than 1ps from 0 Volts to BV min
- High reliability with Planner chips.
- IEC 61000-4-2 ESD 30KV(Air), 30KV(Contact)
- ESD protection of data lines in accordance with IEC 61000-4-2
- EFT protection of data lines in accordance with IEC 61000-4-4
- Halogen free and RoHS compliant
- Lead-free finish


**SMA/DO-214AC**


## Mechanical Characteristics

- CASE: SMAJ (DO-214AC) Molded Plastic over glass passivated junction.
- Mounting Position: Any
- Polarity: by cathode band denotes.
- Terminal: Solder plated

## Maximum Ratings And Characteristics @ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation on 10/1000 us Waveform (Note 1, 2, FIG.1)	P <sub>PPM</sub>	Min 400	W
Power Dissipation on Infinite Heat Sink at T <sub>L</sub> =50°C	P <sub>D</sub>	3.3	W
Peak Pulse Current of on 10/1000us Waveform (Note 1, FIG.3)	I <sub>PPM</sub>	See Table 1	A
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave (Note 2. 3)	I <sub>FSM</sub>	60	A
Operating Junction Temperature Range	T <sub>J</sub>	-55 to 150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to 150	°C

Notes:

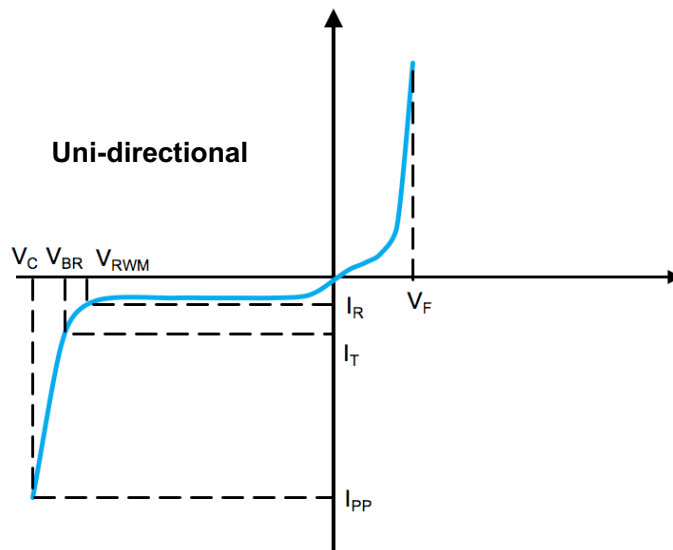
1. Non-repetitive current pulse, per Fig.3 and derated above T<sub>A</sub>=25°C per Fig.2.
2. Mounted on 5.0x5.0mm<sup>2</sup> (0.03mm thick) Copper Pads to each terminal.
3. Measured on 8.3ms single half sine-wave, or equivalent square wave, for Unidirectional device only.

### Electrical Specification @ $T_{amb} 25^{\circ}C$

Type Number	Marking	Reverse Stand-Off Voltage	Breakdown Voltage Min. @ $I_T$	Breakdown Voltage Max. @ $I_T$	Test Current	Maximum Clamping Voltage @ $I_{PP}$	Peak Pulse Current	Reverse Leakage @ $V_{RWM}$
		$V_{RWM}(V)$	$V_{BR MIN}(V)$	$V_{BR MAX}(V)$	$I_T (mA)$	$V_C(V)$	$I_{PP}(A)$	$I_R(\mu A)$
SMAJ3.3A	KC	3.3	5.0	5.8	10	7.6	52.6	100

Remark: typical capacitance is about 1650pF.

### I-V Curve Characteristics



**$P_{PPM}$  Peak Pulse Power Dissipation** - Max power dissipation

**$V_{RWM}$  Reverse Stand-off Voltage** - Maximum voltage that can be applied to TVS without operation

**$V_{BR}$  Breakdown Voltage** – Maximum voltage that flows though the TVS at a specified current ( $I_T$ )

**$V_C$  Clamping Voltage** – Peak voltage measured across the TVS at a specified  $I_{PPM}$  (peak impulse current)

**$I_R$  Reverse Leakage Current** – Current measured at  $V_R$

**$V_F$  Forward Voltage Drop for Uni-directional**

**Ratings and Characteristic Curves** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

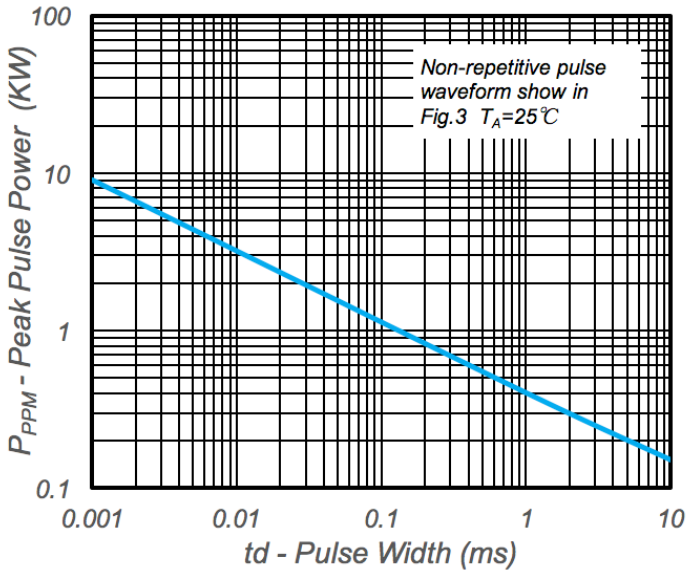


Fig.1 Peak Pulse Power Rating

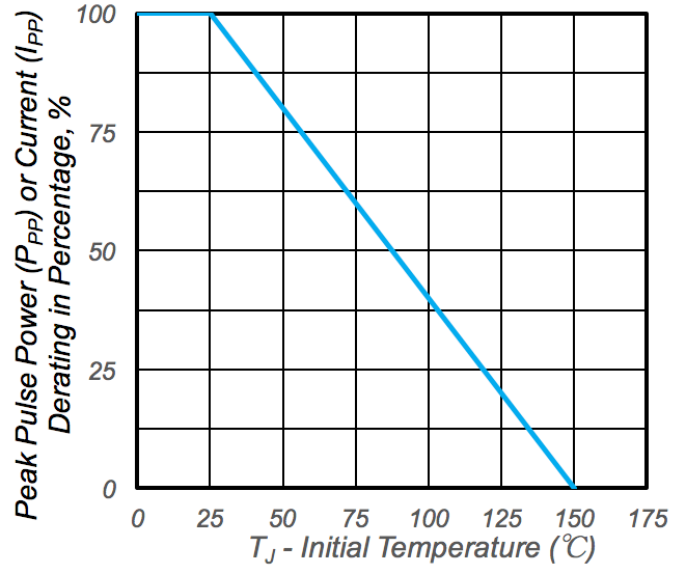


Fig.2 Pulse Derating Curve

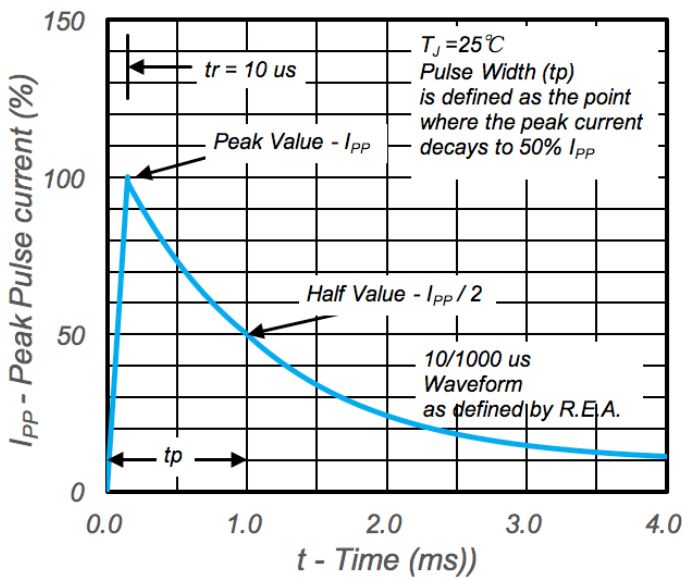
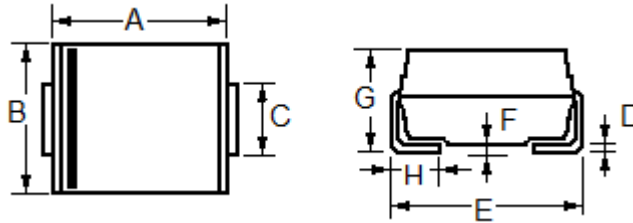


Fig.3 Pulse Waveform

**Package Outline Dimensions and Pad Layouts**
**DO-214AC (SMA)**


Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.99	4.50	0.157	0.177
B	2.54	2.79	0.100	0.110
C	1.25	1.65	0.049	0.065
D	0.152	0.305	0.006	0.012
E	4.93	5.28	0.194	0.208
F	----	0.203	----	0.008
G	1.98	2.29	0.078	0.090
H	0.76	1.52	0.030	0.060